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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN THE MATTER OF THE APPLICATION FOR PATENT

OF: Seiji NAKAHATA et al. | ART UNIT: 2812

SERIAL NO.: 10/535,741 | CONF. NO.: 9438

FILED: May 18, 2005

FOR: METHOD OF PROCESSING SURFACE OF NITRIDE SEMICONDUCTOR
CRYSTAL AND NITRIDE SEMICONDUCTOR CRYSTAL OBTAINED WITH THE
METHOD

COMMISSIONER FOR PATENTS
P.O. BOX 1450
ALEXANDRIA, VA 22313-1450

November 20, 2006

STATUS REQUEST

Dear Sir:

Please inform us of the status of the processing of this
application in the USPTO.

Respectfully submitted
Seiji NAKAHATA et al. - Applicant

WFF:ks/4878

Enclosure:
postcard

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CERTIFICATE OF MAILING:

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Karin Smith - November 20, 2006
Name: Karin Smith - Date: November 20, 2006